Low Capacitance 8 Line EMI Filter with ESD Protection

This device is an 8 line EMI filter array for wireless applications. Greater than -25 dB attenuation is obtained at frequencies from 800 MHz to 2.2 GHz. It also offers ESD protection–clamping transients from static discharges. ESD protection is provided across all capacitors.

Features

- EMI Filtering and ESD Protection
- Integration of 40 Discrete Components
- Compliance with IEC61000-4-2 (Level 4) > 14 kV (Contact)
- DFN Package, 1.6 x 4.0 mm
- Moisture Sensitivity Level 1
- ESD Ratings: Machine Model = C Human Body Model = 3B
- This is a Pb–Free Device*

Benefits

- Reduces EMI/RFI Emmisions on a Data Line
- Integrated Solution Offers Cost and Space Savings
- Reduces Parasitic Inductances Which Offer a More "Ideal" Low Pass Filter Response
- Integrated Solution Improves System Reliability

Applications

- EMI Filtering and ESD Protection for Data Lines
- Wireless Phones
- Handheld Products
- Notebook Computers
- LCD Displays

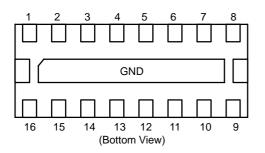


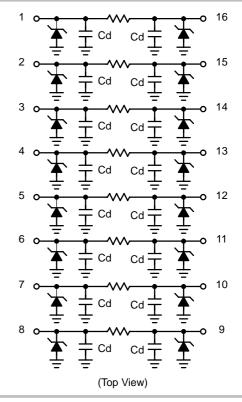
Figure 1. Pin Connections

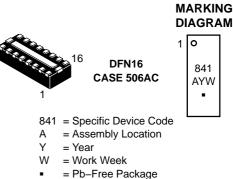
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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http://onsemi.com





ORDERING INFORMATION

Device	Package	Shipping [†]
NUF8401MNT4G	DFN16 (Pb-Free)	4000 / Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MAXIMUM RATINGS

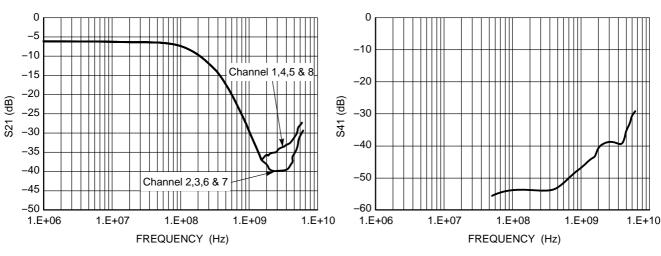
Parameter	Symbol	Value	Unit
ESD Discharge IEC61000–4–2 Contact Discharge	V _{PP}	14	kV
Steady–State Power per Resistor @ 25°C	P _R	328	mW
Operating Temperature Range	T _{OP}	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C
Maximum Lead Temperature for Soldering Purposes (1.8 in from case for 10 seconds)	ΤL	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

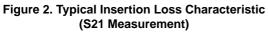
ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Maximum Reverse Working Voltage	V _{RWM}				5.0	V
Breakdown Voltage	V _{BR}	I _R = 1.0 mA	6.0	7.0	8.0	V
Leakage Current	Ι _R	V _{RWM} = 3.3 V			100	nA
Resistance	R _A	l _R = 20 mA	85	100	115	Ω
Capacitance (Notes 1 and 2)	Cd		10	12	15	pF
Cut–Off Frequency (Note 3)	f _{3dB}	Above this frequency, appreciable attenuation occurs		175		MHz

1. Measured at 25°C, $V_R = 2.5 V$, f = 1.0 MHz. 2. Total Line Capacitance is 2 times the Diode Capacitance (Cd). 3. 50 Ω source and 50 Ω load termination.



TYPICAL PERFORMANCE CURVES (T_A= 25°C unless otherwise specified)



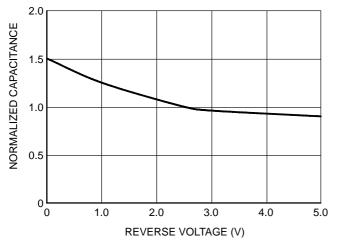


Figure 4. Typical Capacitance vs. Reverse Biased Voltage (Normalized Capacitance Cd at 2.5 V)

Figure 3. Analog Crosstalk Curve (S41 Measurement)

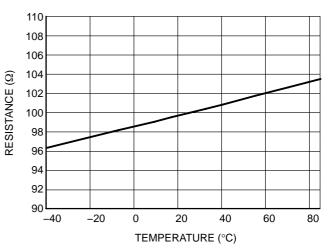
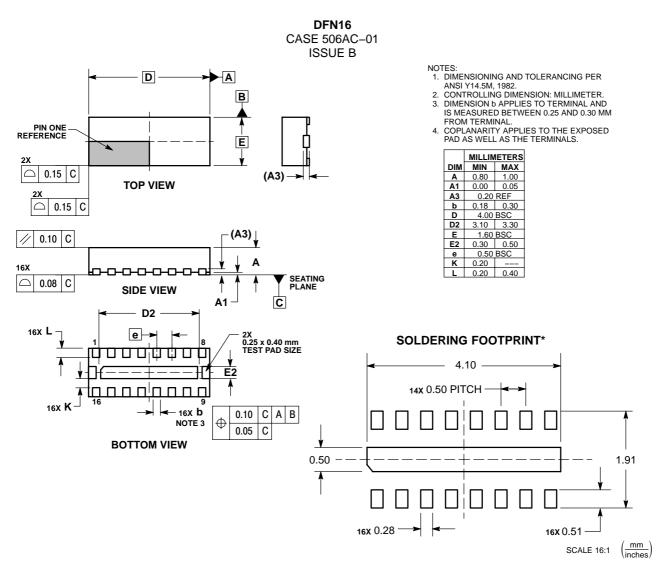


Figure 5. Typical Resistance over Temperature

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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